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1 **IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

2 Application Serial Number 09/292,132
3 Filing Date April 14, 1999
4 Inventor Salman Akram et al.
5 Assignee Micron Technology, Inc.
6 Group Art Number 2812
7 Examiner S. Mulpuri
8 Attorney's Docket No. MI22-1171
9 Title: Methods of Forming a Transistor Gate

10 **INFORMATION DISCLOSURE STATEMENT**

11 References -- See Attached Form PTO-1449

12 The attached form PTO-1449 is submitted in compliance
13 with 37 CFR §1.56. No admission is made regarding whether all the
14 submitted references are prior art.

15 Respectfully submitted,

16 Dated: 1/27/00

17 Attorney:


18 James D. Shaurette
19 Reg. # 39,833

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